

# RBV2500 - RBV2510

**PRV : 50 - 1000 Volts**  
**Io : 25 Amperes**

## FEATURES :

- \* High current capability
- \* High surge current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* High case dielectric strength of 2000 V<sub>DC</sub>
- \* Ideal for printed circuit board
- \* Very good heat dissipation

## MECHANICAL DATA :

- \* Case : Reliable low cost construction utilizing molded plastic technique
- \* Epoxy : UL94V-O rate flame retardant
- \* Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
- \* Polarity : Polarity symbols marked on case
- \* Mounting position : Any
- \* Weight : 7.7 grams

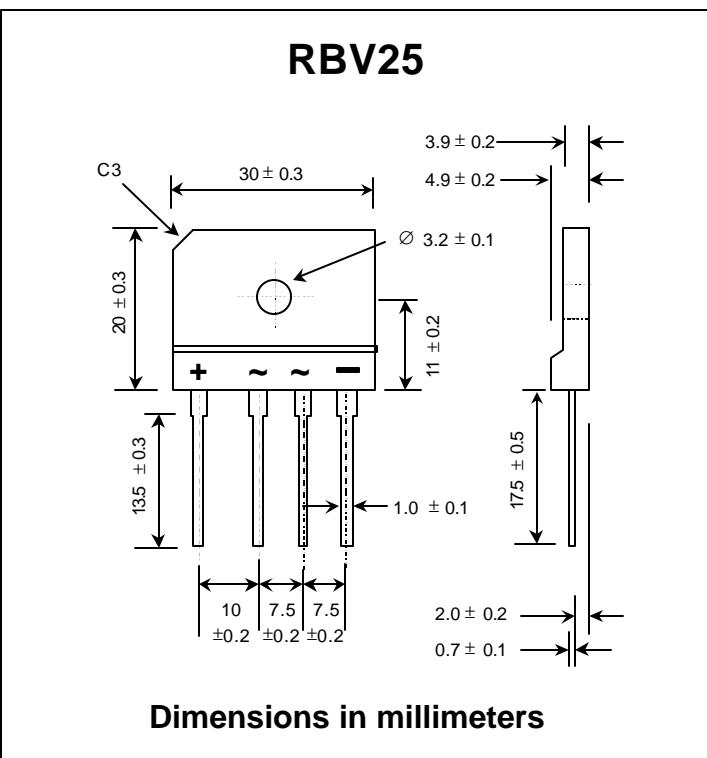
## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

## SILICON BRIDGE RECTIFIERS



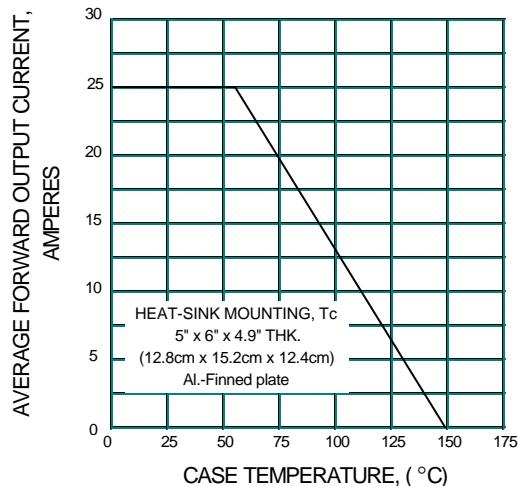
RATING	SYMBOL	RBV 2500	RBV 2501	RBV 2502	RBV 2504	RBV 2506	RBV 2508	RBV 2510	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current T <sub>c</sub> = 55 °C	I <sub>F(AV)</sub>					25			Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>					300			Amps.
Current Squared Time at t < 8.3 ms.	I <sup>2</sup> t				375				A <sup>2</sup> S
Maximum Forward Voltage per Diode at I <sub>F</sub> = 12.5 Amps.	V <sub>F</sub>			1.1					Volts
Maximum DC Reverse Current Ta = 25 °C at Rated DC Blocking Voltage Ta = 100 °C	I <sub>R</sub>			10					µA
	I <sub>R(H)</sub>			200					µA
Typical Thermal Resistance (Note 1)	R <sub>θJC</sub>			1.45					°C/W
Operating Junction Temperature Range	T <sub>J</sub>			- 40 to + 150					°C
Storage Temperature Range	T <sub>STG</sub>			- 40 to + 150					°C

### Notes :

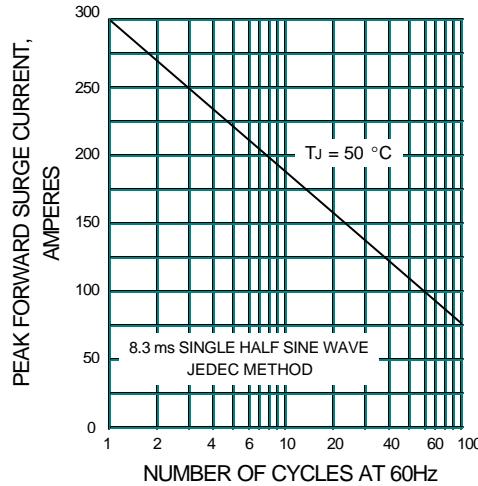
- Thermal resistance from junction to case with units mounted on a 5" x 6" x 4.9" (12.8cm.x 15.2cm.x 12.4cm.) Al.-Finned Plate

## RATING AND CHARACTERISTIC CURVES ( RBV2500 - RBV2510 )

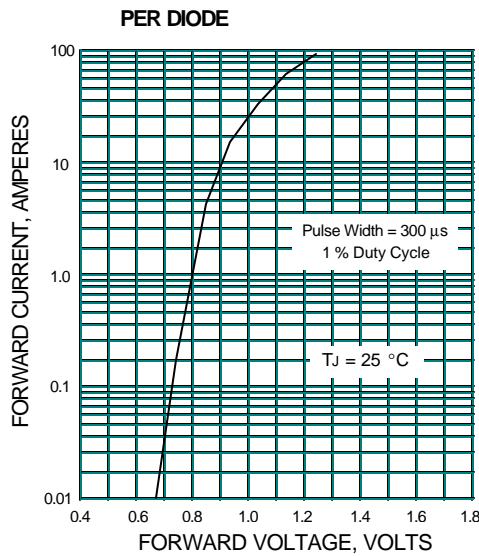
**FIG.1 - DERATING CURVE FOR OUTPUT  
RECTIFIED CURRENT**



**FIG.2 - MAXIMUM NON-REPETITIVE PEAK  
FORWARD SURGE CURRENT**



**FIG.3 - TYPICAL FORWARD CHARACTERISTICS  
PER DIODE**



**FIG.4 - TYPICAL REVERSE CHARACTERISTICS  
PER DIODE**

